



PJD25N04

40V N-Channel Enhancement Mode MOSFET

Voltage

40 V

Current

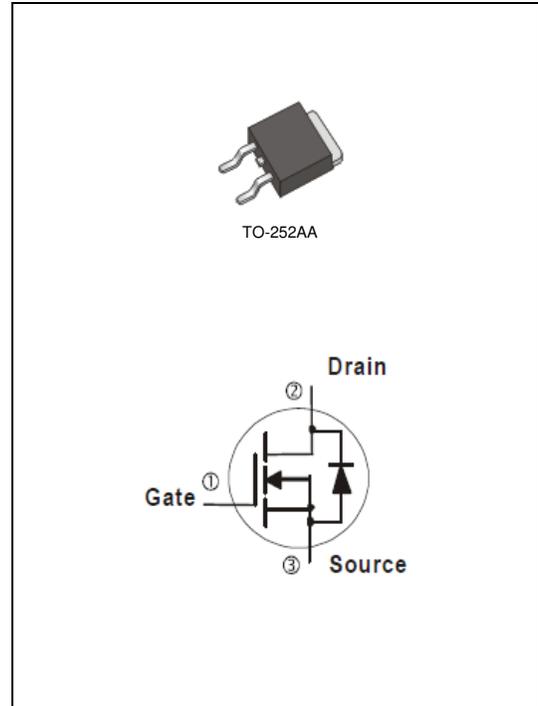
21 A

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@12A < 32m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@10A < 40m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Weight : 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS |
|--|-------------------------|-----------------|----------|--------------------|
| Drain-Source Voltage | | V_{DS} | 40 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | |
| Continuous Drain Current | $T_C=25^\circ\text{C}$ | I_D | 21 | A |
| | $T_C=100^\circ\text{C}$ | | 13.2 | |
| Pulsed Drain Current (Note 1) | $T_C=25^\circ\text{C}$ | I_{DM} | 80 | |
| Power Dissipation | $T_C=25^\circ\text{C}$ | P_D | 25 | W |
| | $T_C=100^\circ\text{C}$ | | 10 | |
| Continuous Drain Current | $T_A=25^\circ\text{C}$ | I_D | 5.9 | A |
| | $T_A=70^\circ\text{C}$ | | 4.7 | |
| Power Dissipation | $T_A=25^\circ\text{C}$ | P_D | 2.0 | W |
| Power Dissipation | $T_A=70^\circ\text{C}$ | | 1.3 | |
| Operating Junction and Storage Temperature Range | | T_J, T_{STG} | -55~150 | $^\circ\text{C}$ |
| Typical Thermal Resistance (Note 4,5) | Junction to Case | $R_{\theta JC}$ | 5.0 | $^\circ\text{C/W}$ |
| | Junction to Ambient | $R_{\theta JA}$ | 62.5 | |

- Limited only By Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|---|--------------|--|------|------|-----------|-------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=250\mu A$ | 40 | - | - | V |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | 1.2 | 1.8 | 2.5 | |
| Drain-Source On-State Resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=12A$ | - | 26 | 32 | mΩ |
| | | $V_{GS}=4.5V, I_D=10A$ | - | 32 | 40 | |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=40V, V_{GS}=0V$ | - | - | 1.0 | μA |
| Gate-Source Leakage Current | I_{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | - | - | ± 100 | nA |
| Dynamic (Note 6) | | | | | | |
| Total Gate Charge | Q_g | $V_{DS}=20V, I_D=5A,$ $V_{GS}=4.5V$ (Note 3) | - | 4.4 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 1.3 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 1.7 | - | |
| Input Capacitance | C_{iss} | $V_{DS}=25V, V_{GS}=0V,$ $f=1.0\text{MHz}$ | - | 425 | - | pF |
| Output Capacitance | C_{oss} | | - | 48 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 36 | - | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD}=20V, I_D=1A,$ $V_{GS}=4.5V, R_G=25\Omega$ (Note 3) | - | 9.4 | - | ns |
| Turn-On Rise Time | t_r | | - | 29 | - | |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 21 | - | |
| Turn-Off Fall Time | t_f | | - | 29 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | I_S | --- | - | - | 21 | A |
| Diode Forward Voltage | V_{SD} | $I_S=1A, V_{GS}=0V$ | - | 0.75 | 1 | V |

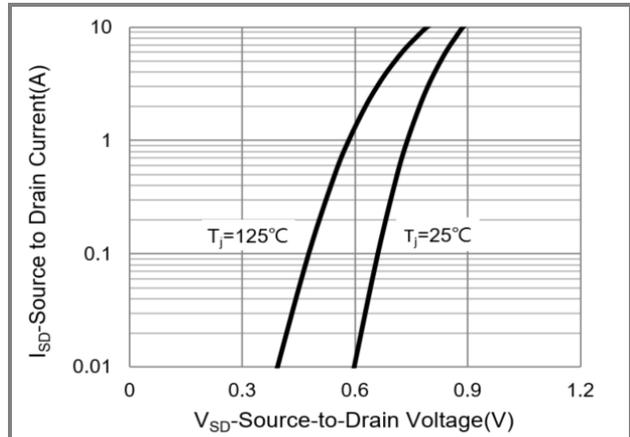
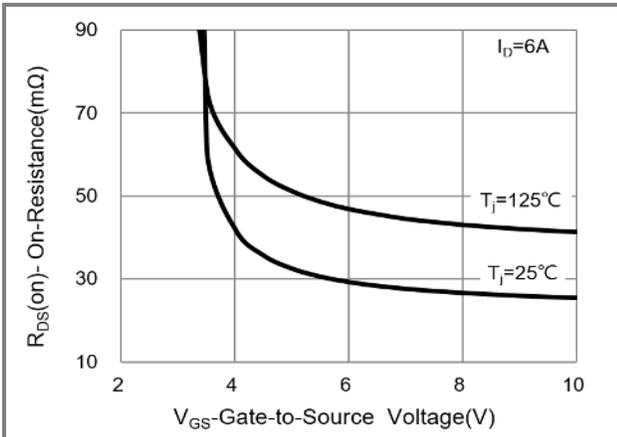
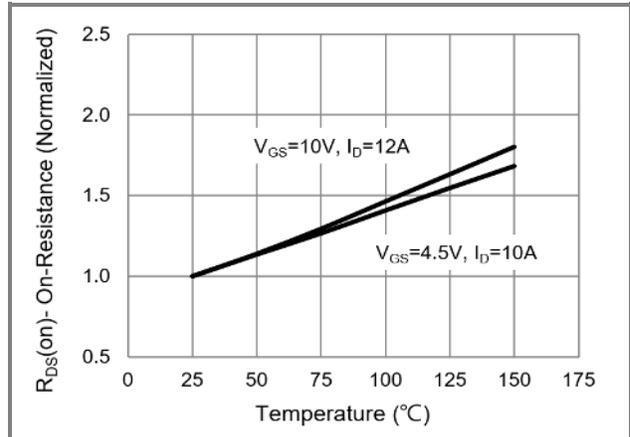
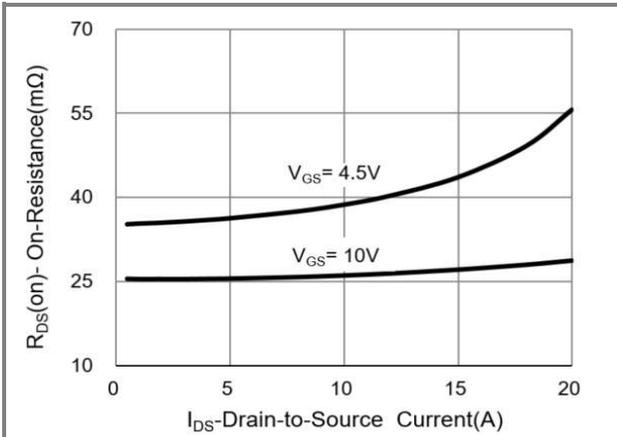
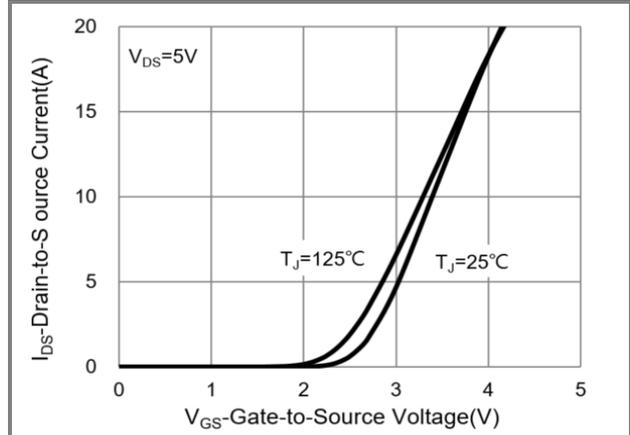
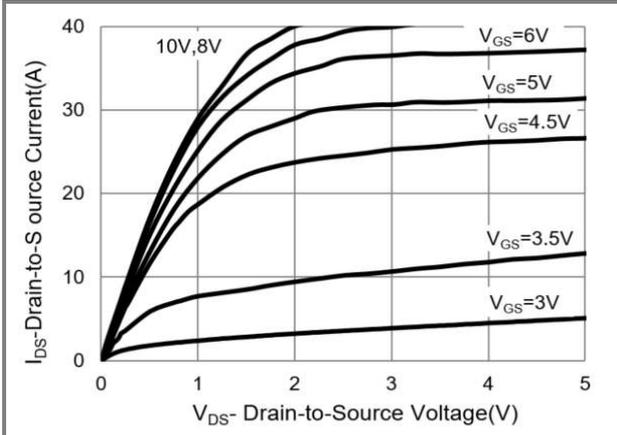
NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^\circ\text{C}$.
4. The maximum current rating is package limited.
5. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.



PJD25N04

TYPICAL CHARACTERISTIC CURVES





PJD25N04

TYPICAL CHARACTERISTIC CURVES

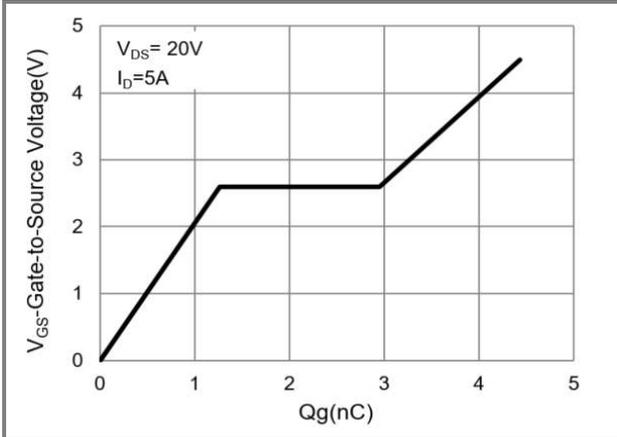


Fig.7 Gate-Charge Characteristics

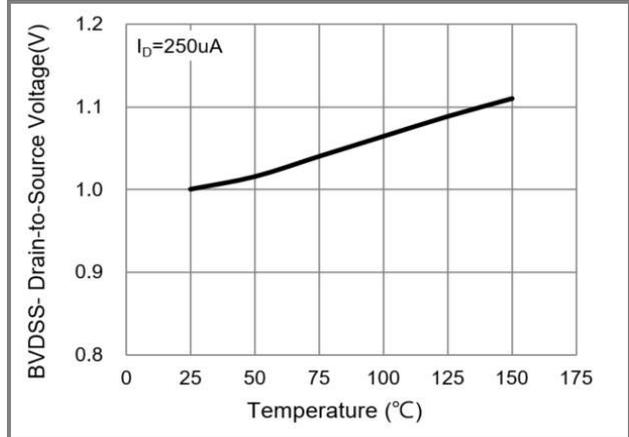


Fig.8 Breakdown Voltage Variation vs. Temperature

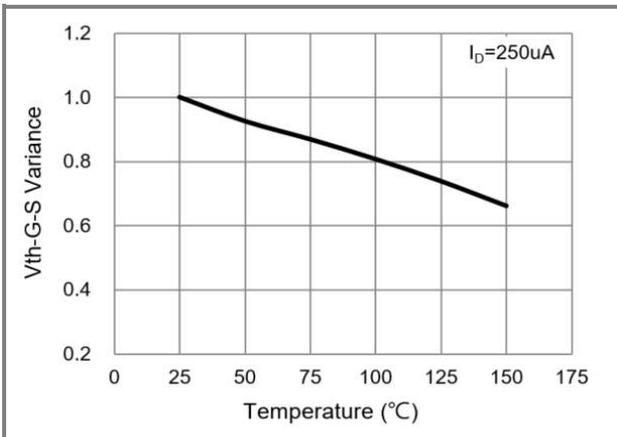


Fig.9 Threshold Voltage Variation with Temperature

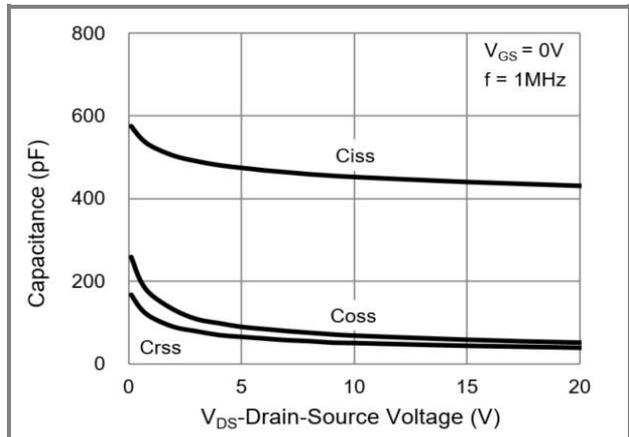


Fig.10 Capacitance vs. Drain-Source Voltage

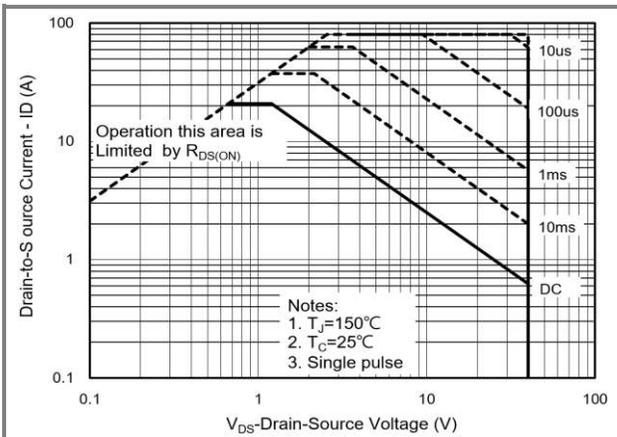


Fig.11 Maximum Safe Operating Area

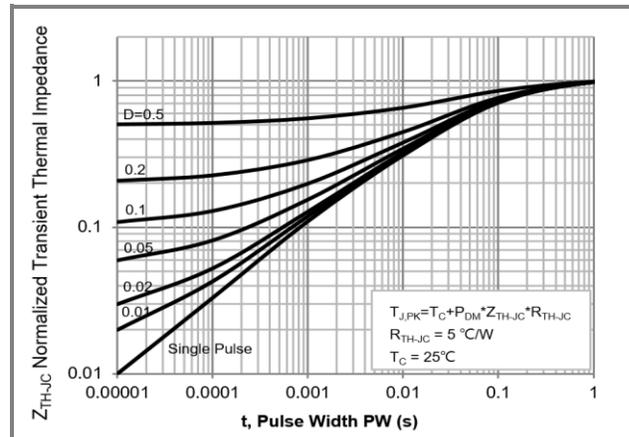


Fig.12 Normalized Transient Thermal Impedance

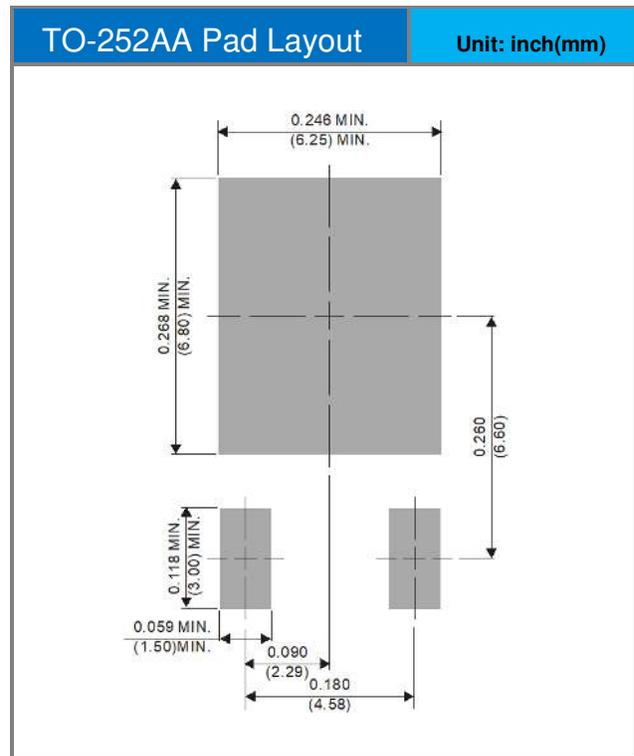
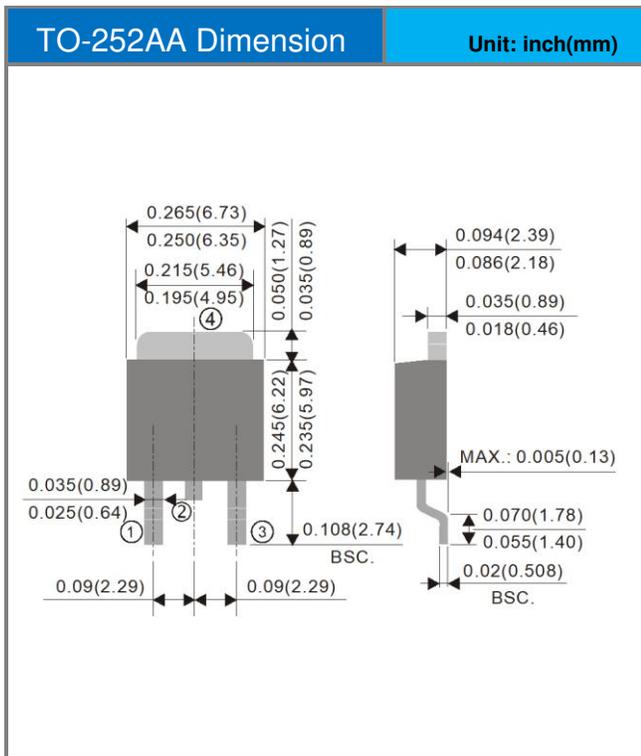


PJD25N04

Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version |
|----------------------|--------------|---------------------|---------|--------------|
| PJD25N04_L2_00001 | TO-252AA | 3,000pcs / 13" reel | D25N04 | Halogen free |

Packaging Information & Mounting Pad Layout





PJD25N04

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